

# DC COMPONENTS CO., LTD.

**RECTIFIER SPECIALISTS** 

W005M THRU W10M

TECHNICAL SPECIFICATIONS OF SINGLE-PHASE SILICON BRIDGE RECTIFIER

VOLTAGE RANGE - 50 to 1000 Volts

CURRENT - 1.5 Amperes

### **FEATURES**

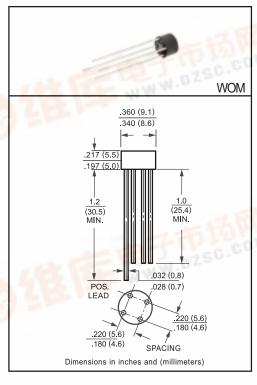
- \* Surge overload ratings to 50 Amperes peak
- \* Good for printed circuit board assembly

### MECHANICAL DATA

- \* Case: Molded plastic
- \* Epoxy: UL 94V-0 rate flame retardant
- \* Lead: MIL-STD-202E, Method 208 guaranteed
- \* Polarity: As marked \* Mounting position: Any
- \* Weight: 1.20 grams

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.



		SYMBOL	W005M	W01M	W02M	W04M	W06M	W80W	W10M	UNITS
Maximum Recurrent Peak Reverse Voltage		VRRM	50	100	200	400	600	800	1000	Volts
Maximum RMS Bridge Input Voltage		VRMS	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage		VDC	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Output Current at TA = 25°C		lo	1.5							Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)		IFSM	50						Amps	
Maximum Forward Voltage Drop per element at 1.0A DC		VF	1.0						Volts	
Maximum Reverse Current at Rated	@TA = 25°C	lR .	10							uAmps
DC Blocking Voltage per element	@TA = 100°C	] IR	500							
I <sup>2</sup> t Rating for Fusing (t<8.3ms)		²t	10							A <sup>2</sup> Sec
Typical Junction Capacitance ( Note1)		Cı	24							pF
Typical Thermal Resistance (Note 2)		RθJA	36							°C/W
Operating Temperature Range		TJ	-55 to + 125							°C
Storage Temperature Range		Тѕтс	-55 to + 150							°C

NOTES: 1.Measured at 1 MHz and applied reverse voltage of 4.0 volts

 $<sup>2. \</sup> Thermal\ Resistance\ from\ Junction\ to\ Ambient\ and\ from\ junction\ to\ lead\ mounted\ on\ P.C.B.\ with\ 0.5\ x\ 0.5"\ (13x13mm)\ copper\ pads.$ 

## RATING AND CHARACTERISTIC CURVES (W005M THRU W10M)

